## 1. General description

NPN/NPN double switching transistor in a SOT666 ultra small and flat lead Surface-Mounted Device (SMD) plastic package.

## 2. Features and benefits

- Double general-purpose switching transistor
- Board-space reduction
- · Ultra small and flat lead SMD plastic package

# 3. Applications

· General-purpose switching and amplification

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transistor						
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	40	V
I <sub>C</sub>	collector current		-	-	200	mA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 1 V; I <sub>C</sub> = 10 mA; T <sub>amb</sub> = 25 °C	100	180	300	

# 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1	6 5 4	C1 B2 E2
2	B1	base TR1		
3	C2	collector TR2		(TR1) TR2)
4	E2	emitter TR2		
5	B2	base TR2	1 2 3	E1 B1 C2
6	C1	collector TR1	SOT666	sym020



## 40 V, 200 mA NPN/NPN switching transistor

# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package	ıckage					
	Name	Description	Version				
PMBT3904VS	SOT666	plastic surface-mounted package; 6 leads	SOT666				

# 7. Marking

### Table 4. Marking codes

Type number	Marking code
PMBT3904VS	ZC

# 8. Limiting values

### Table 5. Limiting values

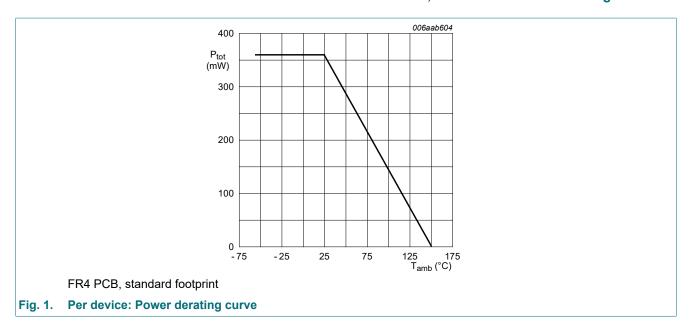
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or		,	'	'	
V <sub>CBO</sub>	collector-base voltage	open emitter		-	60	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	40	V
$V_{EBO}$	emitter-base voltage	open collector		-	6	V
I <sub>C</sub>	collector current			-	200	mA
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	200	mA
I <sub>BM</sub>	peak base current			-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1] [2]	-	240	mW
Per device	-		,	'		
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1] [2]	-	360	mW
T <sub>j</sub>	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

#### 40 V, 200 mA NPN/NPN switching transistor

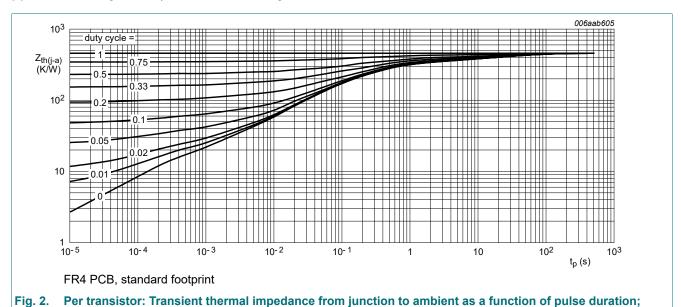


### 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transisto	or						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	521	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	100	K/W
Per device					•	'	<u>'</u>
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	347	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Reflow soldering is the only recommended soldering method.



PMBT3904VS

typical values

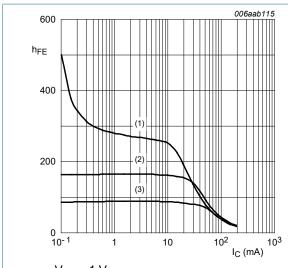
## 40 V, 200 mA NPN/NPN switching transistor

# 10. Characteristics

### **Table 7. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transist	tor					
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = 30 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	50	nA
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 6 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	50	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 1 V; I <sub>C</sub> = 0.1 mA; T <sub>amb</sub> = 25 °C	60	180	-	
		V <sub>CE</sub> = 1 V; I <sub>C</sub> = 1 mA; T <sub>amb</sub> = 25 °C	80	180	-	
		V <sub>CE</sub> = 1 V; I <sub>C</sub> = 10 mA; T <sub>amb</sub> = 25 °C	100	180	300	
		V <sub>CE</sub> = 1 V; I <sub>C</sub> = 50 mA; T <sub>amb</sub> = 25 °C	60	105	-	
		$V_{CE}$ = 1 V; $I_{C}$ = 100 mA; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	30	50	-	
V <sub>CEsat</sub>	collector-emitter	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 1 mA; T <sub>amb</sub> = 25 °C	-	75	200	mV
	saturation voltage	I <sub>C</sub> = 50 mA; I <sub>B</sub> = 5 mA; T <sub>amb</sub> = 25 °C	-	120	300	mV
V <sub>BEsat</sub>	base-emitter saturation voltage	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 1 mA; T <sub>amb</sub> = 25 °C	650	750	850	mV
		I <sub>C</sub> = 50 mA; I <sub>B</sub> = 5 mA; T <sub>amb</sub> = 25 °C	-	850	950	mV
t <sub>d</sub>	delay time	I <sub>C</sub> = 10 mA; I <sub>Bon</sub> = 1 mA; I <sub>Boff</sub> = -1 mA;	-	-	35	ns
t <sub>r</sub>	rise time	V <sub>CC</sub> = 3 V; T <sub>amb</sub> = 25 °C	-	-	35	ns
t <sub>on</sub>	turn-on time		-	-	70	ns
t <sub>s</sub>	storage time		-	-	200	ns
t <sub>f</sub>	fall time		-	-	50	ns
t <sub>off</sub>	turn-off time		-	-	250	ns
C <sub>c</sub>	collector capacitance	$V_{CB} = 5 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A}; f = 1 \text{ MHz}; $ $T_{amb} = 25 \text{ °C}$	-	-	4	pF
C <sub>e</sub>	emitter capacitance	$V_{EB}$ = 500 mV; $I_{C}$ = 0 A; $i_{c}$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C	-	-	8	pF
f <sub>T</sub>	transition frequency	$V_{CE} = 20 \text{ V}; I_{C} = 10 \text{ mA}; f = 100 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$	300	-	-	MHz
NF	noise figure	$V_{CE}$ = 5 V; $I_{C}$ = 100 μA; $R_{S}$ = 1 kΩ; 10 Hz ≤ f ≤ 15700 Hz; $T_{amb}$ = 25 °C	-	-	5	dB

### 40 V, 200 mA NPN/NPN switching transistor



(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

Per transistor: DC current gain as a function of Fig. 3. collector current; typical values

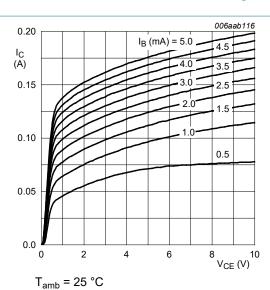
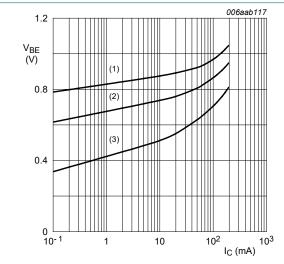


Fig. 4. Per transistor: Collector current as a function of collector-emitter voltage; typical values



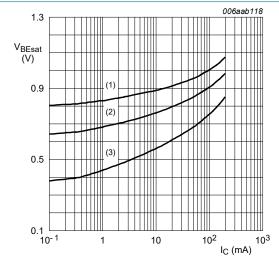
 $V_{CE} = 1 V$ 

(1)  $T_{amb} = -55 \, ^{\circ}C$ 

(2) T<sub>amb</sub> = 25 °C

(3)  $T_{amb} = 150 \, ^{\circ}C$ 

Fig. 5. Per transistor: Base-emitter voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 10$ 

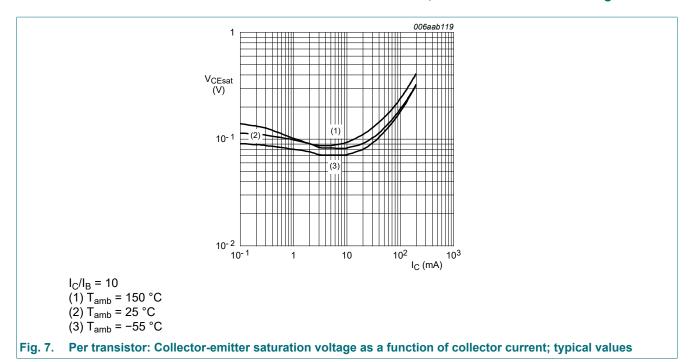
(1)  $T_{amb} = -55$  °C

(2)  $T_{amb} = 25 \, ^{\circ}C$ 

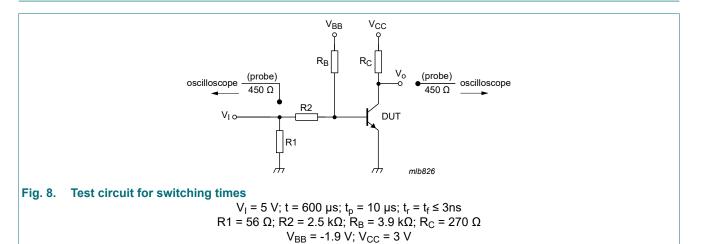
(3)  $T_{amb} = 150 \, ^{\circ}C$ 

Fig. 6. Per transistor: Base-emitter saturation voltage as a function of collector current; typical values

## 40 V, 200 mA NPN/NPN switching transistor

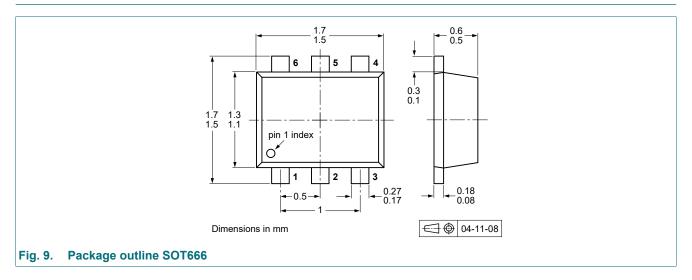


## 11. Test information

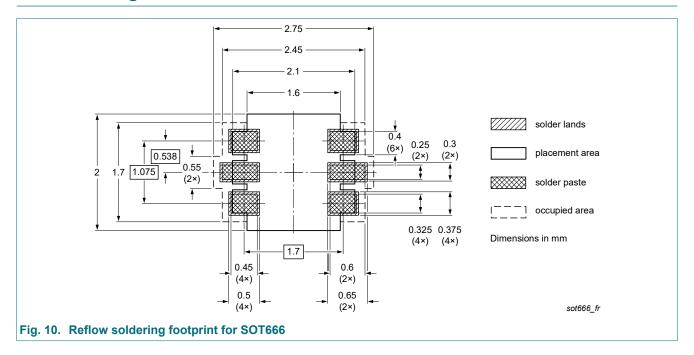


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# 12. Package outline



# 13. Soldering



## 40 V, 200 mA NPN/NPN switching transistor

# 14. Revision history

## Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes					
PMBT3904VS v. 2	20190917	Product data sheet	-	PMBT3904VS v. 1					
Modifications:	of Nexperia.	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>							
PMBT3904VS v. 1	20090708	Product data sheet	-	-					

## 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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## 40 V, 200 mA NPN/NPN switching transistor

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